

30V N-Channel Mosfet

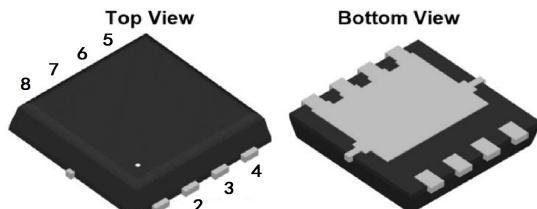
**FEATURES**

- RDS(ON) < 5.0mΩ @ VGS = 10V
- RDS(ON) < 7.5mΩ @ VGS = 4.5V

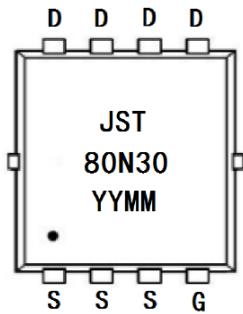
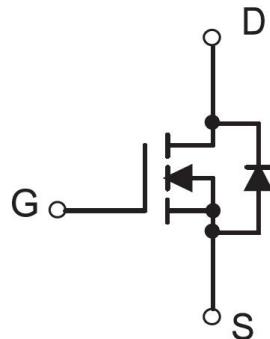
**APPLICATIONS**

- PWM Applications
- Load Switch
- Power Management

PDFNWB5×6-8L



1: S	3: S	5: D	7: D
2: S	4: G	6: D	8: D

**MARKING****N-CHANNEL MOSFET**

YYMM:Date Code(year&amp;month)

**Maximum ratings ( $T_a=25^\circ\text{C}$  unless otherwise noted)**

Symbol	Parameter		Max.	Units
$V_{DSS}$	Drain-Source Voltage		30	V
$V_{GSS}$	Gate-Source Voltage		$\pm 20$	V
$I_D$	Continuous Drain Current	$T_C = 25^\circ\text{C}$	60	A
		$T_C = 100^\circ\text{C}$	39	A
$I_{DM}$	Pulsed Drain Current <sup>note1</sup>		240	A
$E_{AS}$	Single Pulsed Avalanche Energy <sup>note2</sup>		85	mJ
$P_D$	Power Dissipation	$T_C = 25^\circ\text{C}$	31	W
$R_{\theta JC}$	Thermal Resistance, Junction to Case		4	$^\circ\text{C}/\text{W}$
$T_J, T_{STG}$	Operating and Storage Temperature Range		-55 to +150	$^\circ\text{C}$

**Electrical Characteristics** ( $T_J=25^\circ\text{C}$  unless otherwise specified)

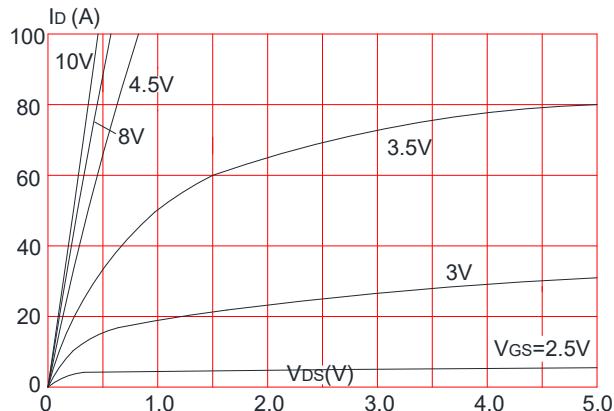
Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
<b>Off Characteristic</b>						
$V_{(\text{BR})\text{DSS}}$	Drain-Source Breakdown Voltage	$V_{GS}=0\text{V}$ , $I_D=250\mu\text{A}$	30	-	-	V
$I_{\text{DSS}}$	Zero Gate Voltage Drain Current	$V_{DS}=30\text{V}$ , $V_{GS}=0\text{V}$ ,	-	-	1.0	$\mu\text{A}$
$I_{GSS}$	Gate to Body Leakage Current	$V_{DS}=0\text{V}$ , $V_{GS}=\pm 20\text{V}$	-	-	$\pm 100$	nA
<b>On Characteristics</b>						
$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{DS}=V_{GS}$ , $I_D=250\mu\text{A}$	1.0	1.5	2.5	V
$R_{DS(\text{on})}$ note3	Static Drain-Source on-Resistance	$V_{GS}=10\text{V}$ , $I_D=30\text{A}$	-	3.8	5	$\text{m}\Omega$
		$V_{GS}=4.5\text{V}$ , $I_D=20\text{A}$	-	7.5	11	
<b>Dynamic Characteristics</b>						
$C_{iss}$	Input Capacitance	$V_{DS}=15\text{V}$ , $V_{GS}=0\text{V}$ , $f=1.0\text{MHz}$	-	2100	-	pF
$C_{oss}$	Output Capacitance		-	326	-	pF
$C_{rss}$	Reverse Transfer Capacitance		-	282	-	pF
$Q_g$	Total Gate Charge	$V_{DS}=15\text{V}$ , $I_D=30\text{A}$ , $V_{GS}=10\text{V}$	-	45	-	nC
$Q_{gs}$	Gate-Source Charge		-	3	-	nC
$Q_{gd}$	Gate-Drain("Miller") Charge		-	15	-	nC
<b>Switching Characteristics</b>						
$t_{d(on)}$	Turn-on Delay Time	$V_{DS}=15\text{V}$ , $I_D=30\text{A}$ , $R_{\text{GEN}}=3\Omega$ , $V_{GS}=10\text{V}$	-	21	-	ns
$t_r$	Turn-on Rise Time		-	32	-	ns
$t_{d(off)}$	Turn-off Delay Time		-	59	-	ns
$t_f$	Turn-off Fall Time		-	34	-	ns
<b>Drain-Source Diode Characteristics and Maximum Ratings</b>						
$I_s$	Maximum Continuous Drain to Source Diode Forward Current	-	-	60	A	
$I_{SM}$	Maximum Pulsed Drain to Source Diode Forward Current	-	-	240	A	
$V_{SD}$	Drain to Source Diode Forward Voltage	$V_{GS}=0\text{V}$ , $I_s=30\text{A}$	-	-	1.2	V
$trr$	Body Diode Reverse Recovery Time	$I_F=20\text{A}$ , $dI/dt=100\text{A}/\mu\text{s}$	-	15	-	ns
$Qrr$	Body Diode Reverse Recovery Charge		-	4	-	nC

Notes:1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature

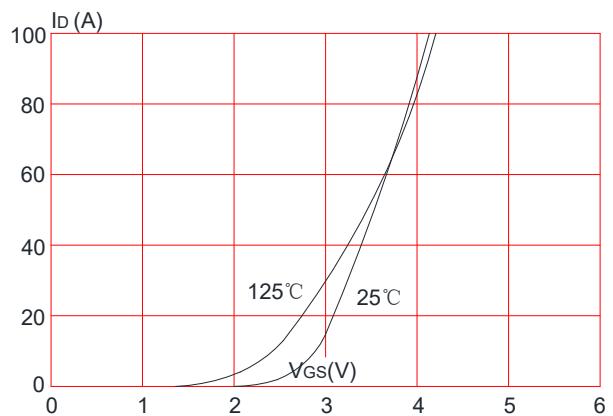
2. EAS condition:  $T_J=25^\circ\text{C}$ ,  $V_{DD}=15\text{V}$ ,  $V_G=10\text{V}$ ,  $R_G=25\Omega$ ,  $L=0.5\text{mH}$ ,  $I_{AS}=18.4\text{A}$ 3. Pulse Test: Pulse Width $\leq 300\mu\text{s}$ , Duty Cycle $\leq 0.5\%$

## Typical Performance Characteristics

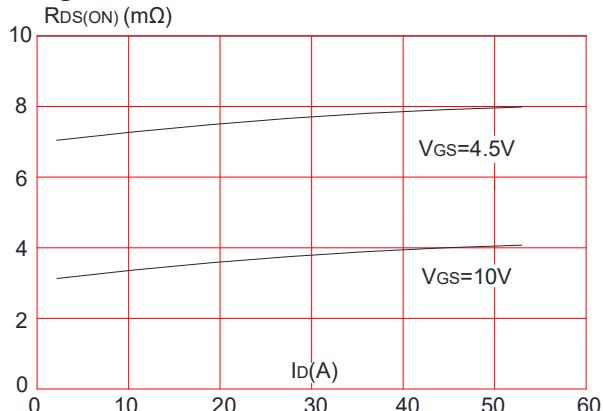
**Figure 1:** Output Characteristics



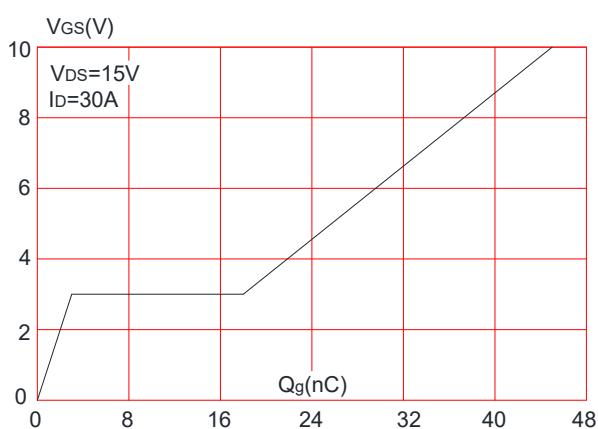
**Figure 2:** Typical Transfer Characteristics



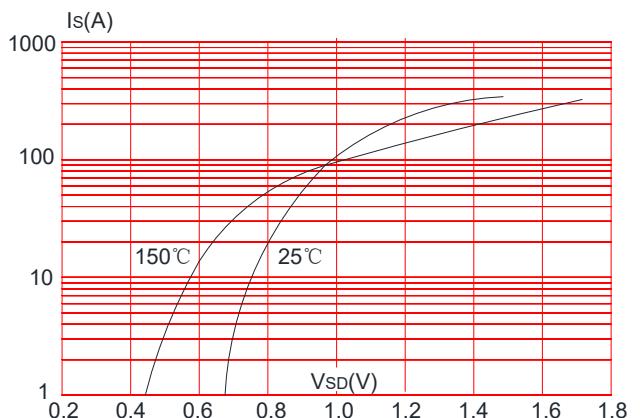
**Figure 3:** On-resistance vs. Drain Current



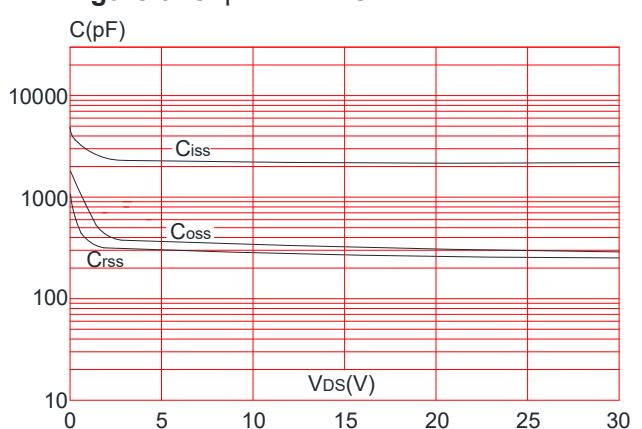
**Figure 5:** Gate Charge Characteristics



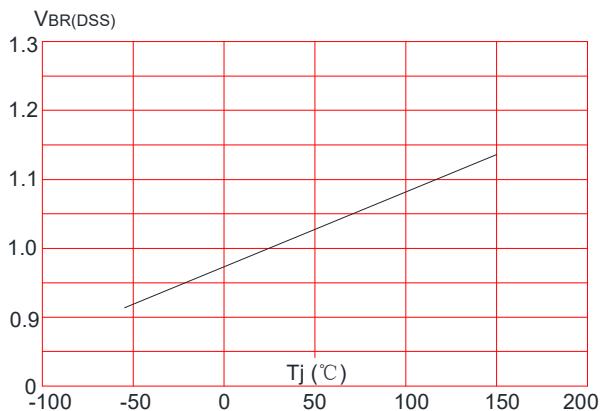
**Figure 4:** Body Diode Characteristics



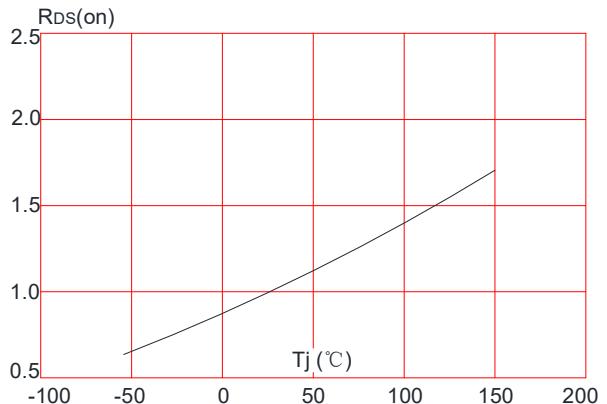
**Figure 6:** Capacitance Characteristics



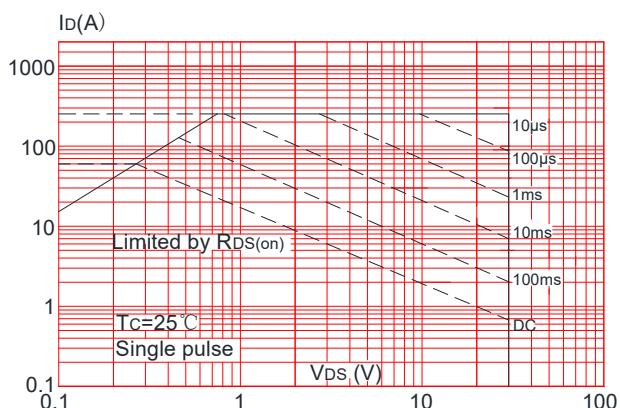
**Figure 7:** Normalized Breakdown Voltage vs. Junction Temperature



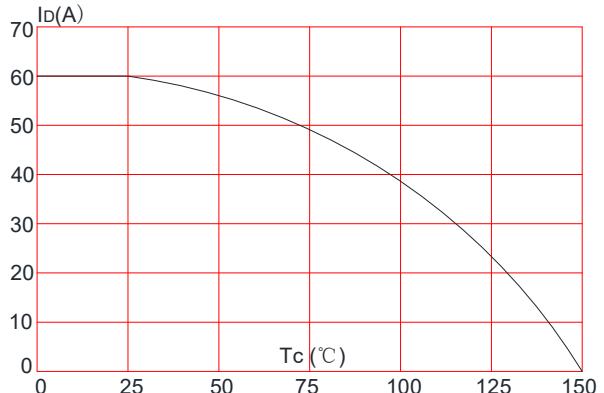
**Figure 8:** Normalized on Resistance vs. Junction Temperature



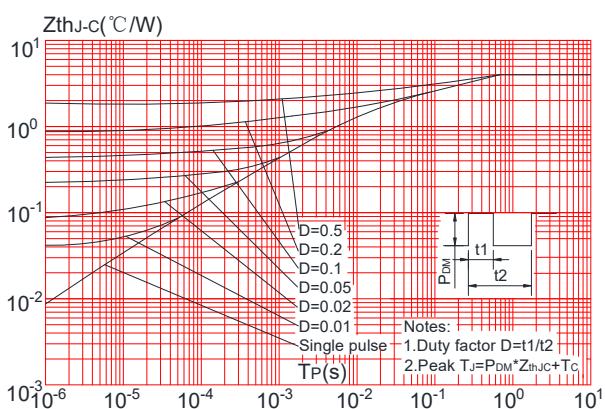
**Figure 9:** Maximum Safe Operating Area



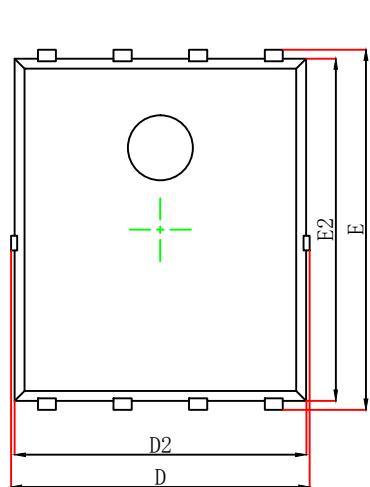
**Figure 10:** Maximum Continuous Drain Current vs. Case Temperature



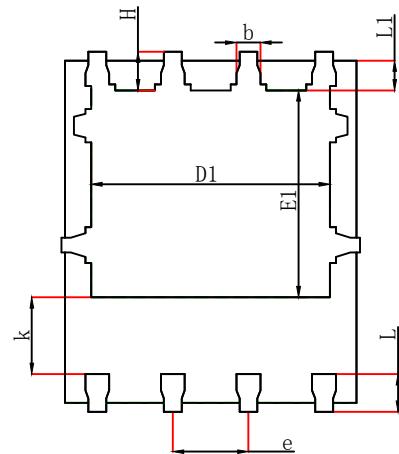
**Figure 11:** Maximum Effective Transient Thermal Impedance, Junction-to-Case



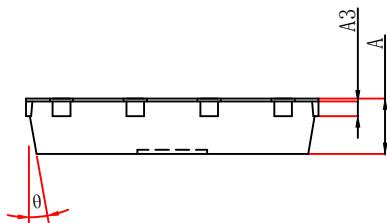
## PDFNWB5×6-8L(P1.27T0.95) PACKAGE OUTLINE DIMENSIONS



Top View  
[頂襪囊]



Bottom View  
[底襪囊]



Side View  
[側襪囊]

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.000	0.035	0.039
A3	0.254REF.		0.010REF.	
D	4.944	5.096	0.195	0.201
E	5.974	6.126	0.235	0.241
D1	3.910	4.110	0.154	0.162
E1	3.375	3.575	0.133	0.141
D2	4.824	4.976	0.190	0.196
E2	5.674	5.826	0.223	0.229
k	1.190	1.390	0.047	0.055
b	0.350	0.450	0.014	0.018
e	1.270TYP.		0.050TYP.	
L	0.559	0.711	0.022	0.028
L1	0.424	0.576	0.017	0.023
H	0.574	0.726	0.023	0.029
θ	10°	12°	10°	12°